

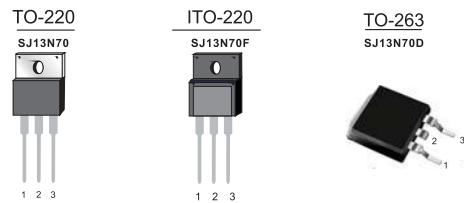
## FEATURES

- $R_{DS(on)} < 0.38\Omega$  @  $V_{GS} = 10V$
- 100% avalanche tested
- RoHS compliant

Product Summary			
$V_{DS}$	$R_{DS(on)}$ ( $\Omega$ ) Typ	$I_D$ (A)	$Q_g$ (Typ)
700V	0.36 @ 10V	13	34nC

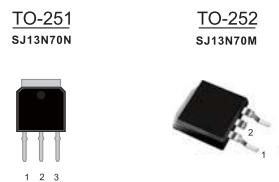
## MECHANICAL DATA

- Case: TO-220, ITO-220, TO-251, TO-252, TO-263 package



## Ordering Information

Part No.	Package Type	Package	Quality(box)
SJ13N70	TO-220	Tube	1000
SJ13N70F	ITO-220	Tube	1000
SJ13N70E	TO-263	Tape & Reel	800
SJ13N70M	TO-252	Tape & Reel	3000
SJ13N70N	TO-251	Tube	1000



### Pin Definition:

1. Gate
2. Drain
3. Source

## Block Diagram

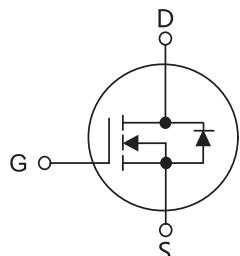


Table 1 Absolute Maximum Ratings ( $T_c=25^\circ C$ , unless otherwise specified)

Parameter	Symbol	TO-220/TO-263 TO-251/TO-252	ITO-220	Unit
Drain-Source Voltage	$V_{DS}$	700		V
Gate-Source Voltage	$V_{GS}$	$\pm 30$		V
Continuous Drain Current $T_c=25^\circ C$	$I_D$	13		A
$T_c=100^\circ C$		9		
Pulsed Drain Current (Note 1)	$I_{DM}$	46		A
Single Pulse Avalanche Energy (Note 2)	$E_{AS}$	280		mJ
Avalanche Current (Note 1)	$I_{AR}$	2.3		A
Repetitive Avalanche Energy (Note 1)	$E_{AR}$	1.2		mJ
Peak Diode Recovery dv/dt (Note 3)	$dv/dt$	15		V/ns
Drain Source voltage slope ( $V_{DS}=480V$ )	$dV_{DS}/dt$	50		V/ns
Power Dissipation $T_c=25^\circ C$	$P_D$	151	35	W
Operating Junction and Storage Temperature	$T_J/T_{STG}$	$-55 \sim +150$		°C
Maximum Temperature for soldering	$T_L$	300		°C

# SJ13N70 Series

Table 2.Thermal Characteristics

Parameter	Symbol	TO-220/TO-263	ITO-220	Unit
Thermal resistance Junction to Ambient	R <sub>θJA</sub>	62	62	°C/W
Thermal resistance Junction to Case	R <sub>θJC</sub>	0.82	3.57	°C/W

Table 3. Electrical Characteristics (T<sub>J</sub>=25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	V <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	700	--	--	V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =700V, V <sub>GS</sub> =0V	--	--	1	μA
Gate- Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =30V, V <sub>DS</sub> =0V	--	--	100	nA
		V <sub>GS</sub> =-30V, V <sub>DS</sub> =0V	--	--	-100	nA
On Characteristics(Note 4)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2.5	--	4.5	V
Static Drain-Source On-State Resistance	R <sub>DSON</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =6.5A	--	0.36	0.38	Ω
Dynamic Characteristics(Note 5)						
Input Capacitance	C <sub>ISS</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHz	--	780	--	pF
Output Capacitance	C <sub>OSS</sub>		--	23	--	pF
Reverse Transfer Capacitance	C <sub>RSS</sub>		--	1.9	--	pF
Switching Characteristics (Note 5)						
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =400V, I <sub>D</sub> =6.5A, R <sub>G</sub> =20Ω	--	17	--	ns
Turn-On Rise Time	t <sub>r</sub>		--	12	--	ns
Turn-Off Delay Time	t <sub>d(off)</sub>		--	130	--	ns
Turn-Off Fall Time	t <sub>f</sub>		--	10	--	ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DS</sub> =400V, I <sub>D</sub> =6.5A, V <sub>GS</sub> =10V	--	34	--	nC
Gate-Source Charge	Q <sub>GS</sub>		--	4.5	--	nC
Gate-Drain Charge	Q <sub>GD</sub>		--	19	--	nC
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =6.5A	--	0.9	1.5	V
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>		--	--	10	A
Reverse Recovery Time	t <sub>rr</sub>	V <sub>GS</sub> =0V, I <sub>F</sub> =6.5A dI <sub>F</sub> /dt=100A/μs (Note 1)	--	300	--	ns
Reverse Recovery Charge	Q <sub>RR</sub>		--	3500	--	nC

Notes : 1 Repetitive Rating:Pulse width limited by maximum junction temperature

2 I<sub>AS</sub>=3A, V<sub>DD</sub>=150V, Starting T<sub>J</sub>=25°C

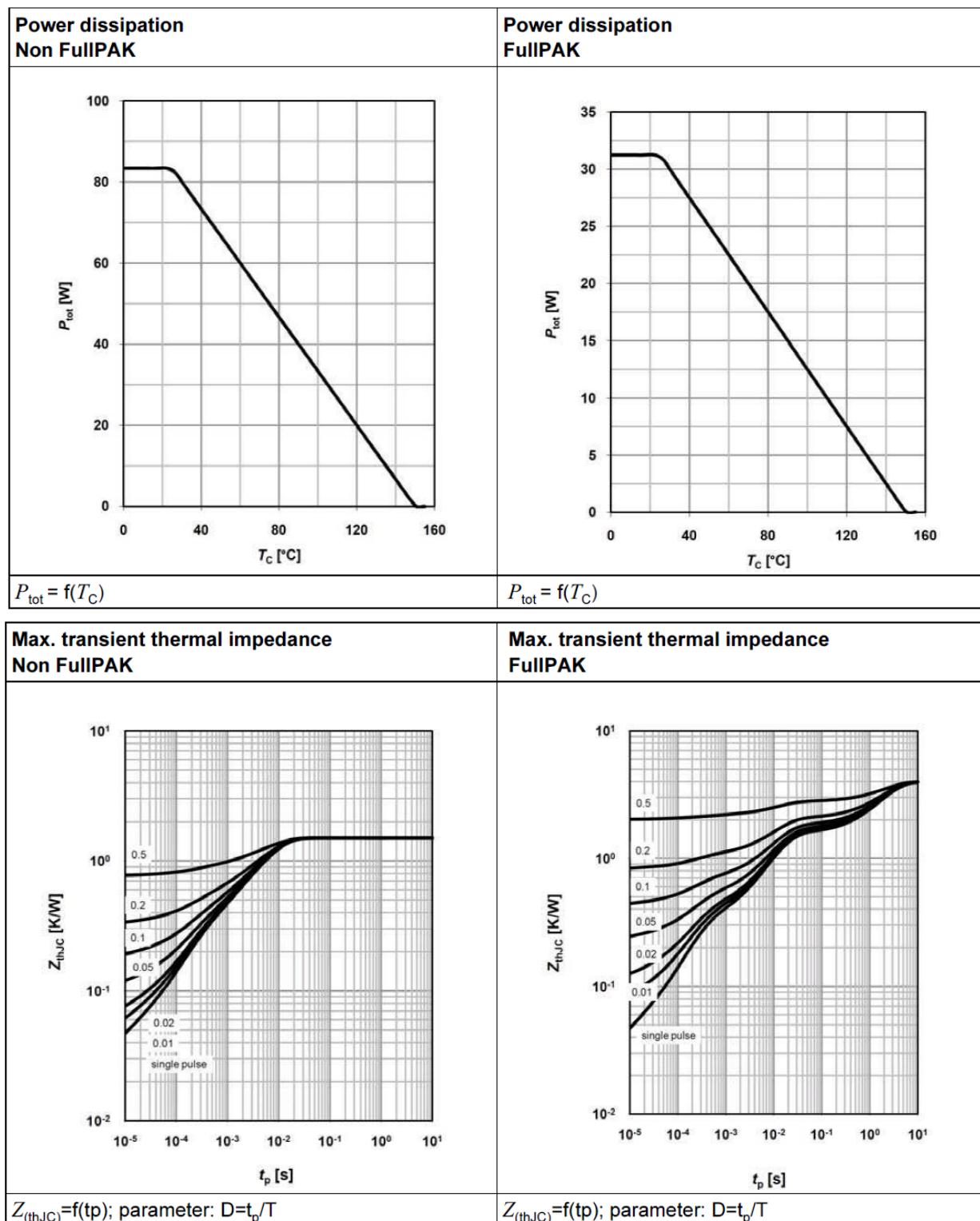
3 I<sub>SD</sub>≤I<sub>D</sub>, di/dt≤200A/μs, V<sub>DD</sub>≤BVDSS, Starting T<sub>J</sub>=25°C

4 Pulse Test: Pulse width ≤300μS, Duty cycle≤2%

5 Guaranteed by design,not subject to production

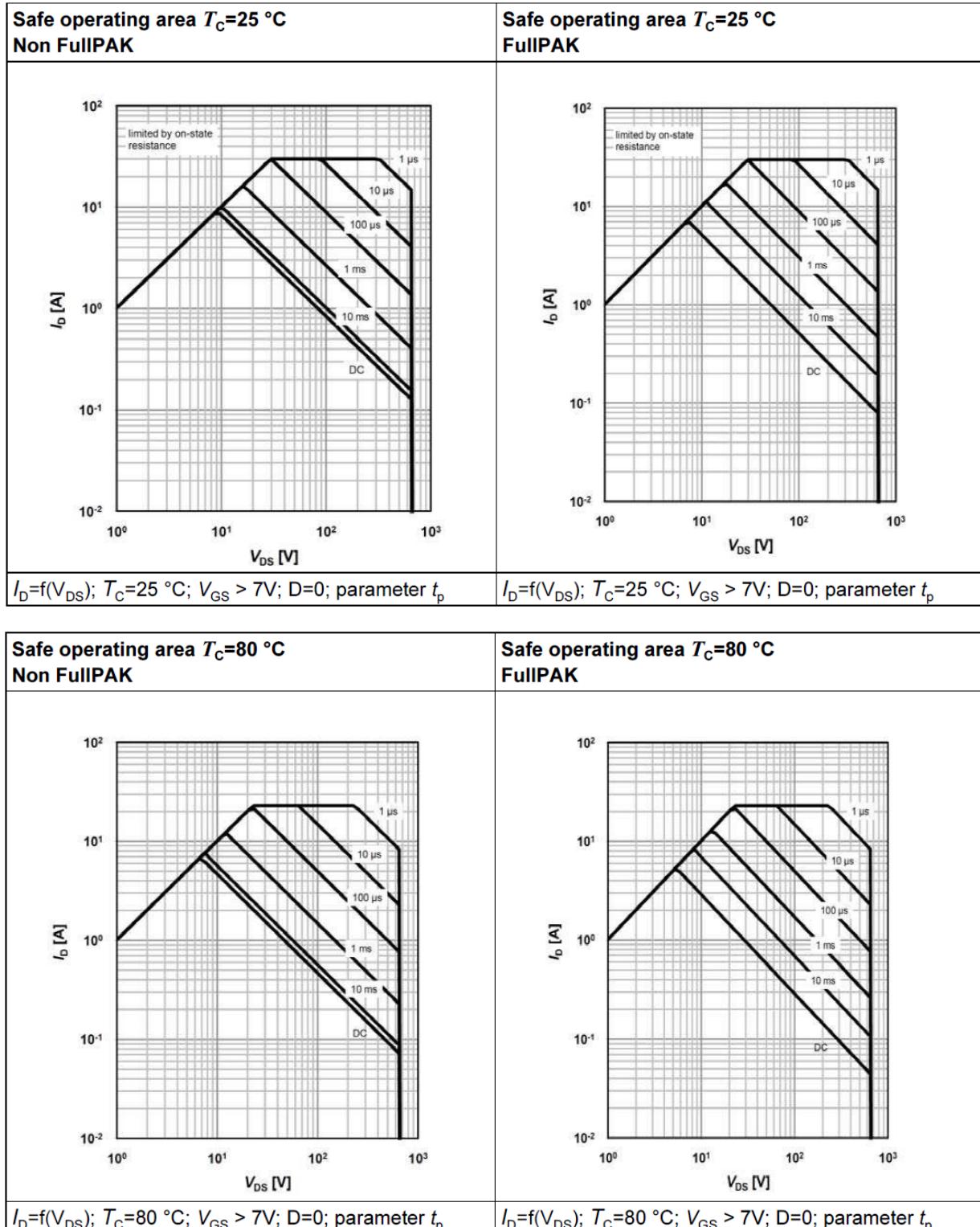
# SJ13N70 Series

## Typical characteristics Diagrams



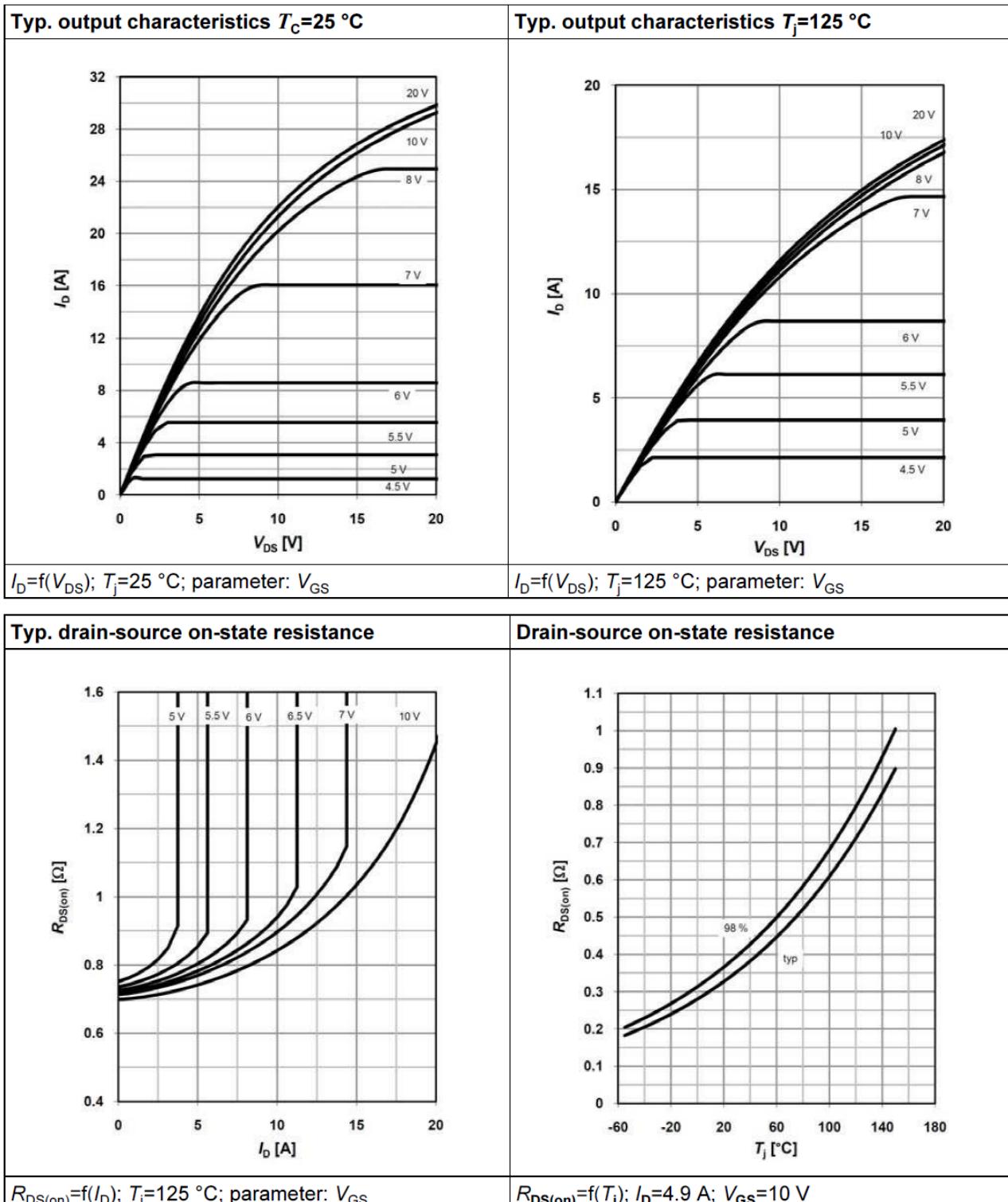
# SJ13N70 Series

## Typical characteristics Diagrams



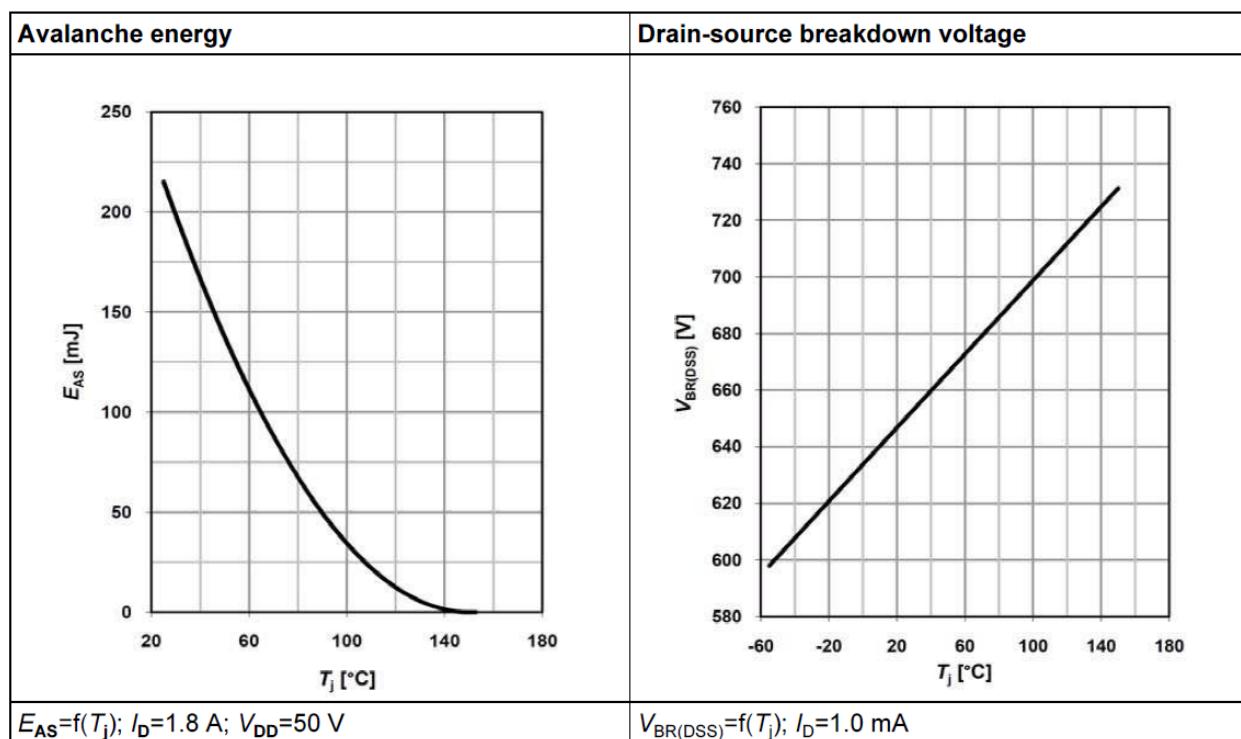
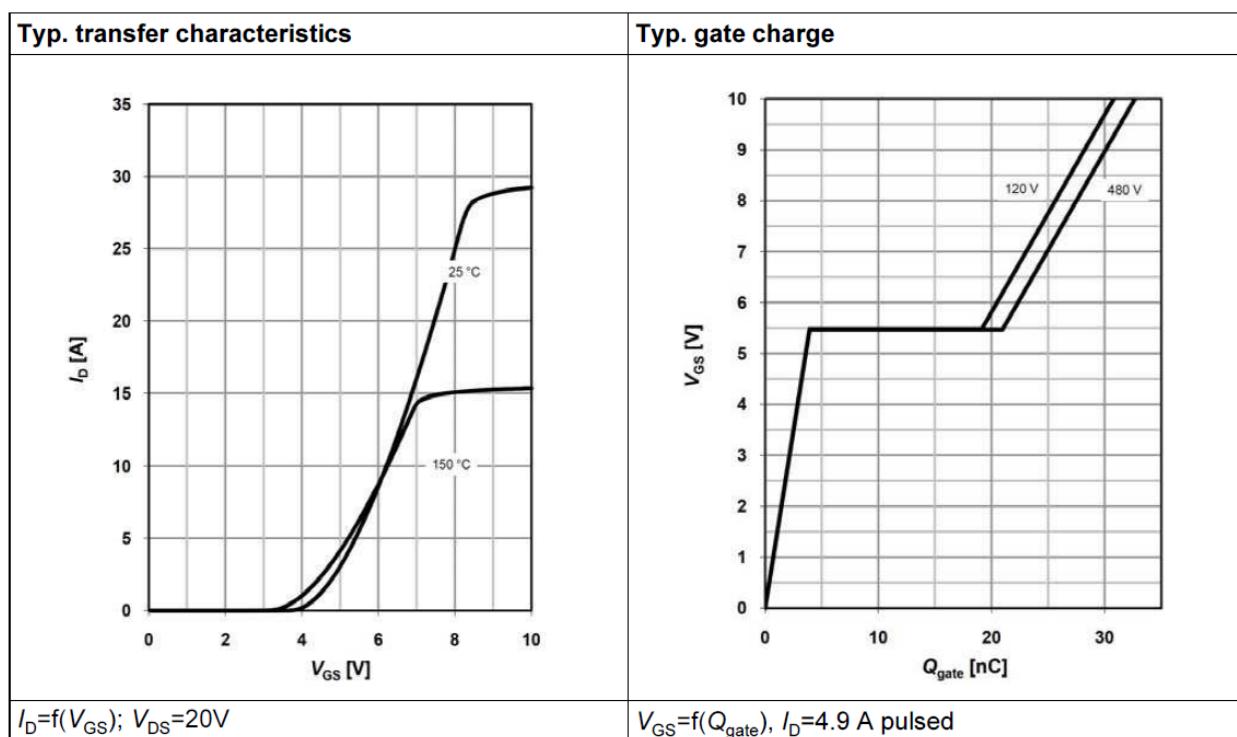
# SJ13N70 Series

## Typical characteristics Diagrams



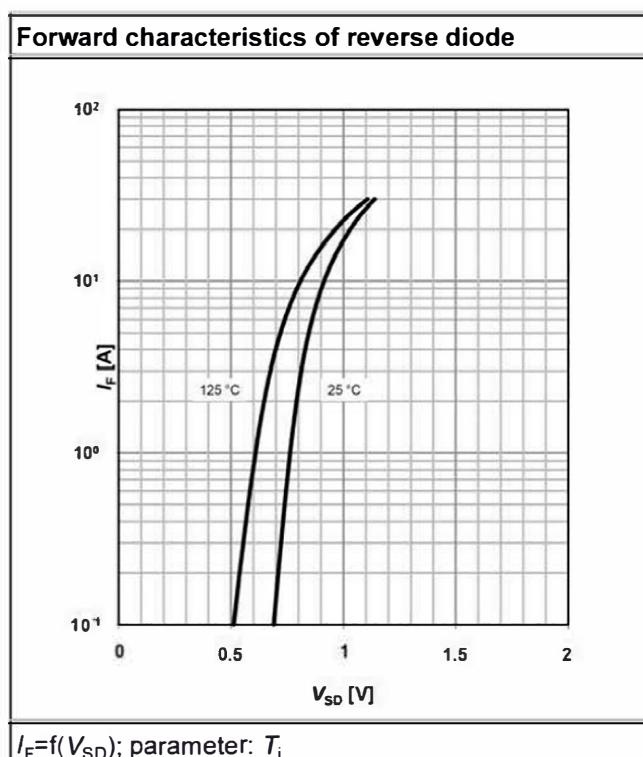
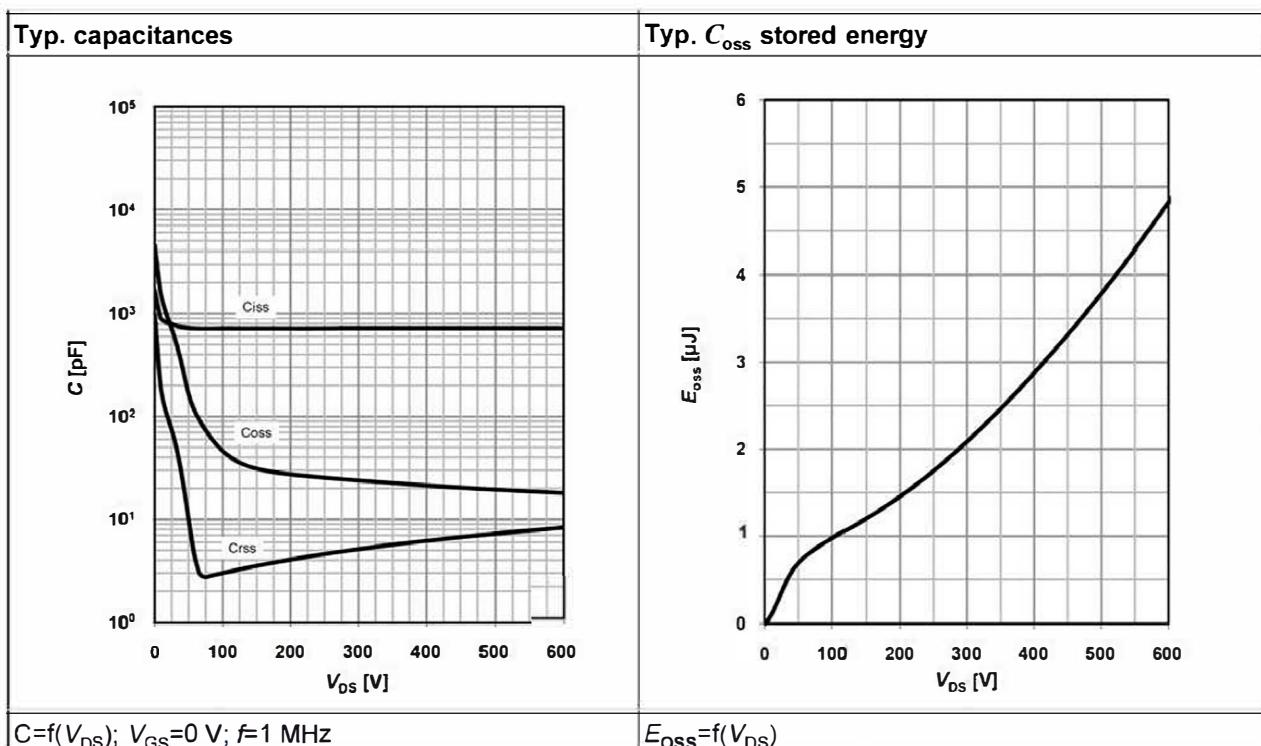
# SJ13N70 Series

## Typical characteristics Diagrams



# SJ13N70 Series

## Typical characteristics Diagrams



# SJ13N70 Series

## Typical characteristics Diagrams

Table 20 Switching times test circuit and waveform for inductive load

Switching times test circuit for inductive load	Switching time waveform

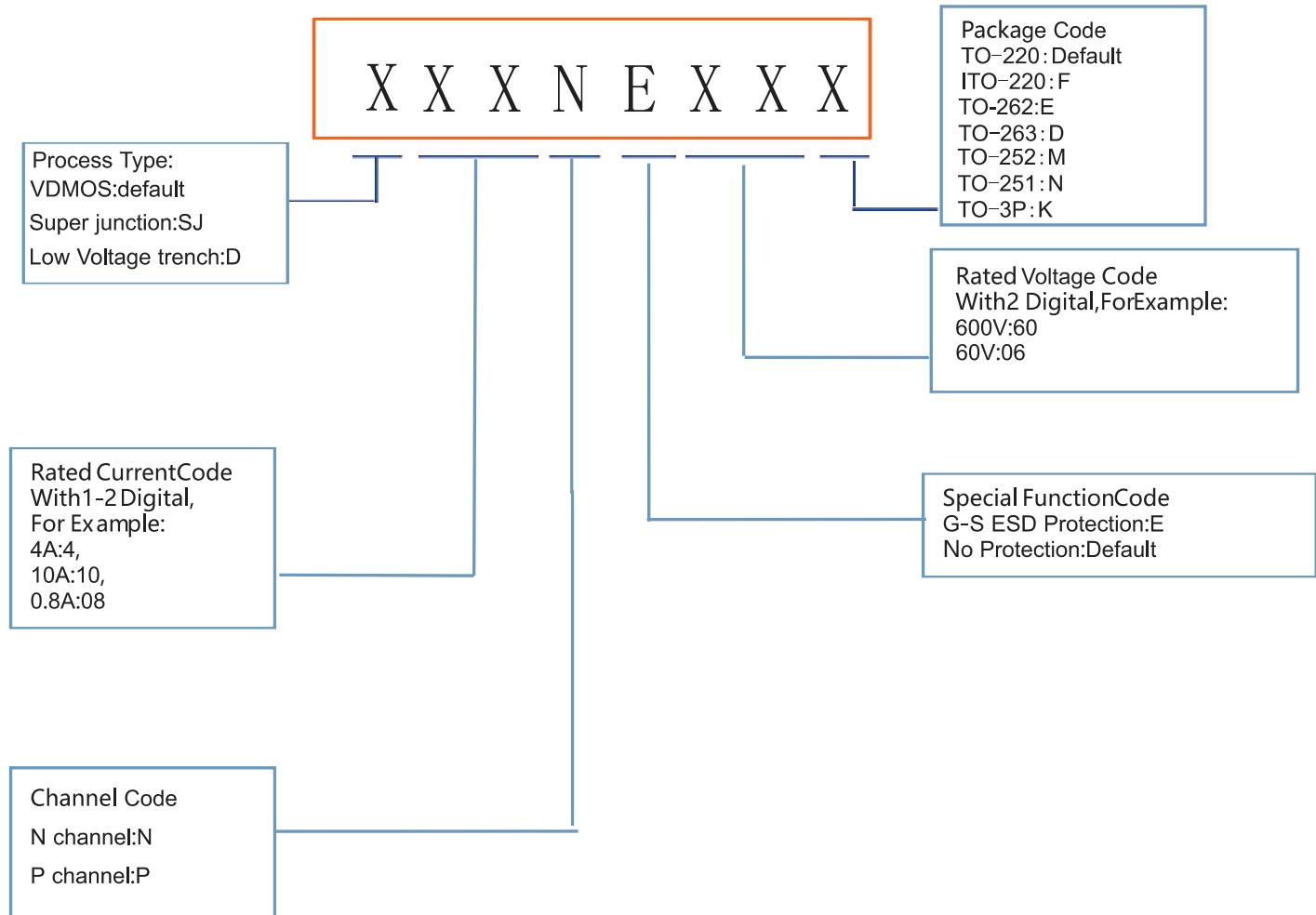
Table 21 Unclamped inductive load test circuit and waveform

Unclamped inductive load test circuit	Unclamped inductive waveform

Table 22 Test circuit and waveform for diode characteristics

Test circuit for diode characteristics	Diode recovery waveform

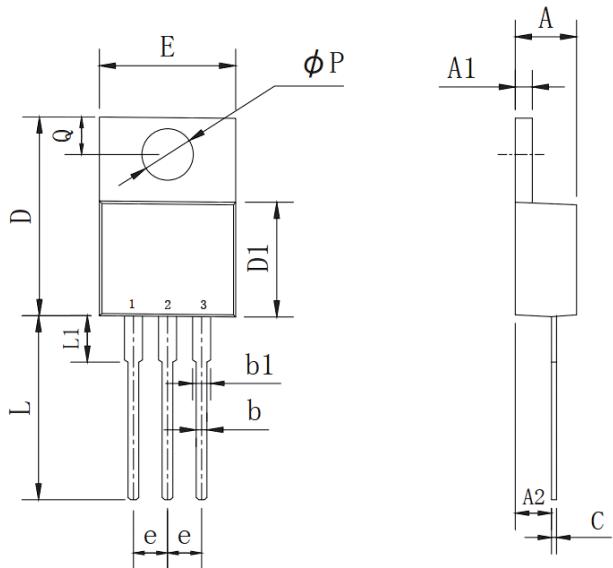
## Product Names Rules



# SJ13N70 Series

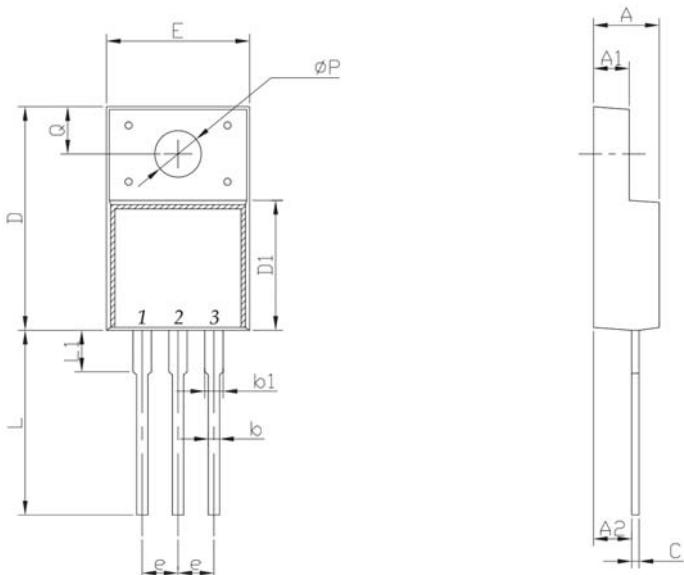
## Dimensions

### TO-220 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	4.25	4.87	0.167	0.192
A1	1.07	1.47	0.042	0.058
A2	2.03	2.92	0.080	0.115
b	0.51	1.11	0.020	0.044
b1	0.97	1.6	0.038	0.063
C	0.3	0.7	0.012	0.028
D	14.6	15.9	0.575	0.626
D1	8.04	9.3	0.317	0.366
E	9.57	10.57	0.377	0.416
e	2.34	2.74	0.092	0.108
L	12.58	14.3	0.495	0.563
L1	2.8	4.2	0.110	0.165
P	3.4	4.14	0.134	0.163
Q	2.45	3	0.096	0.118

### ITO-220 PACKAGE OUTLINE DIMENSIONS

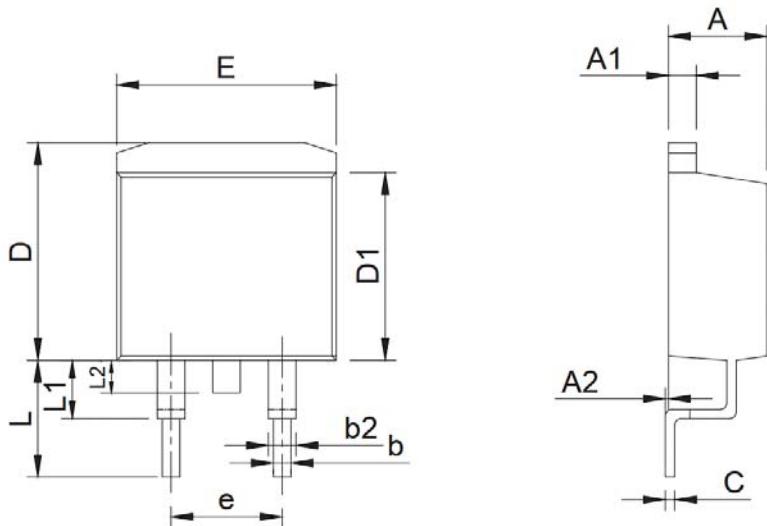


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	4.24	4.9	0.167	0.193
A1	2.3	2.92	0.091	0.115
A2	2.61	2.81	0.103	0.111
b	0.3	1	0.012	0.039
b1	0.9	1.55	0.035	0.061
C	0.3	0.7	0.012	0.028
D	14.5	16.36	0.571	0.644
D1	8.8	9.41	0.346	0.370
E	9.5	10.5	0.374	0.413
e	2.3	2.75	0.091	0.108
L	12.6	14	0.496	0.551
L1	2.45	4.3	0.096	0.169
P	2.9	3.8	0.114	0.150
Q	2.5	3.55	0.098	0.140

# SJ13N70 Series

## Dimensions

### TO-263 PACKAGE OUTLINE DIMENSIONS

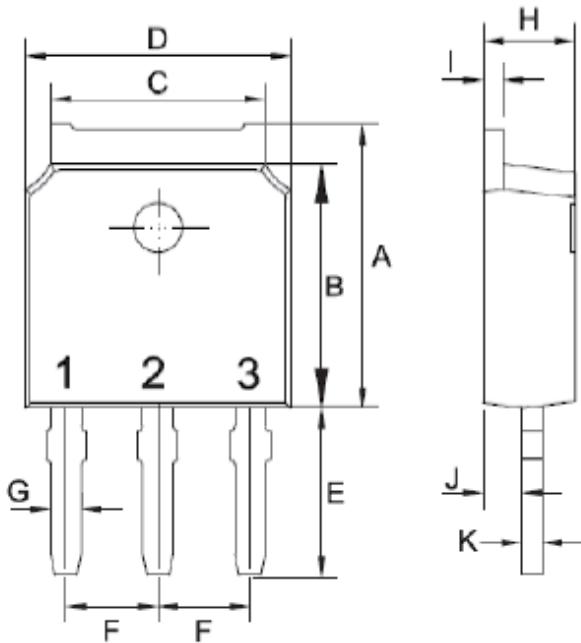


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	4.25	4.87	0.167	0.192
A1	1.07	1.47	0.042	0.058
A2	0	0.25	0.000	0.010
b	0.61	1.01	0.024	0.040
b1	1.2	1.34	0.047	0.053
C	0.3	0.6	0.012	0.024
D	9.48	10.84	0.373	0.427
D1	8.49	9.3	0.334	0.366
E	9.7	10.31	0.382	0.406
e	4.88	5.28	0.192	0.208
L	4.46	5.85	0.176	0.230
L1	1.33	2.33	0.052	0.092
L2	0	2.2	0.000	0.087

# SJ13N70 Series

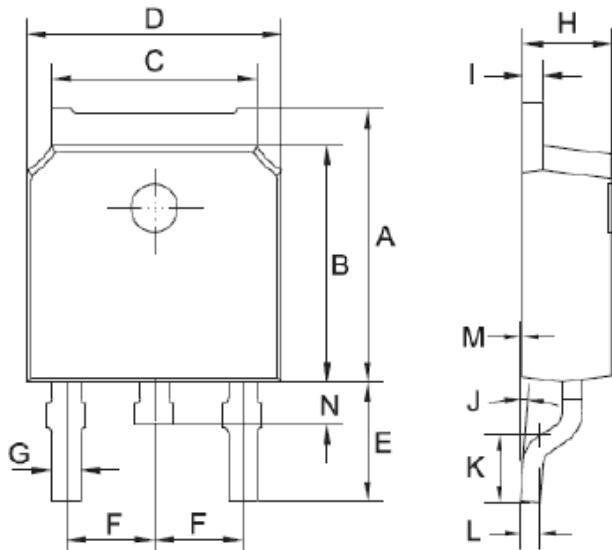
## Dimensions

### TO-251 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	6.85	7.25	0.270	0.285
B	5.8	6.3	0.228	0.248
C	5	5.53	0.197	0.218
D	6.3	6.8	0.248	0.268
E	3.5	4.35	0.138	0.171
F	2.19	2.39	0.086	0.094
G	0.45	0.85	0.018	0.033
H	2.2	2.4	0.087	0.094
I	0.41	0.61	0.016	0.024
J	0.71	1.31	0.028	0.052
K	0.41	0.61	0.016	0.024

### TO-252 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	6.85	7.25	0.270	0.285
B	5.8	6.3	0.228	0.248
C	5	5.53	0.197	0.218
D	6.3	6.8	0.248	0.268
E	2.6	3.3	0.102	0.130
F	2.19	2.39	0.086	0.094
G	0.45	0.85	0.018	0.033
H	2.2	2.4	0.087	0.094
I	0.41	0.61	0.016	0.024
J	0°	8°	0°	8°
K	1.45	1.85	0.057	0.073
L	0.41	0.61	0.016	0.024
M	0	0.12	0.000	0.005
N	0.6	1	0.024	0.039

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